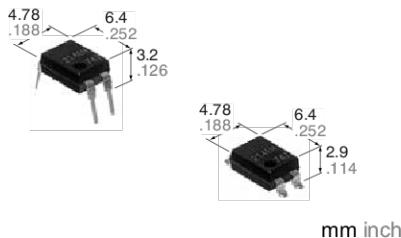


Panasonic

ideas for life

**General use and economy type.
DIP (1 Form A) 4-pin type.
Reinforced insulation
5,000V type.**

**GU-E PhotoMOS
(AQY210EH)**



FEATURES

1. Reinforced insulation 5,000 V type

More than 0.4 mm internal insulation distance between inputs and outputs. Conforms to EN41003, EN60950 (reinforced insulation).

2. Compact 4-pin DIP size

The device comes in a compact (W)6.4×(L)4.78×(H)3.2mm (W).252×(L).188×(H).126inch, 4-pin DIP size.

3. Controls low-level analog signals

PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

4. High sensitivity, low ON resistance

Can control a maximum 0.13 A load current with a 5 mA input current. Low ON resistance of 25Ω (AQY210EH).

Stable operation because there are no metallic contact parts.

5. Low-level off state leakage current

The SSR has an off state leakage current of several milliamperes, whereas the PhotoMOS relay has typ. 100 pA even with the rated load voltage of 350 V (AQY210EH).

TYPICAL APPLICATIONS

- Modem
- Telephone equipment
- Security equipment
- Sensors

TYPES

Type	I/O isolation voltage	Output rating*		Part No.				Packing quantity			
		Load voltage	Load current	Through hole terminal		Surface-mount terminal					
				Tube packing style		Tape and reel packing style		Tube	Tape and reel		
		Reinforced 5,000 V	30 V	1,000 mA	AQY211EH	AQY211EHA	AQY211EHAX	AQY211EHAZ			
AC/DC type			60 V	550 mA	AQY212EH	AQY212EHA	AQY212EHAX	AQY212EHAZ			
			350 V	130 mA	AQY210EH	AQY210EHA	AQY210EHAX	AQY210EHAZ			
			400 V	120 mA	AQY214EH	AQY214EHA	AQY214EHAX	AQY214EHAZ			
			600 V	50 mA	AQY216EH	AQY216EHA	AQY216EHAX	AQY216EHAZ			
									1 tube contains 100 pcs. 1 batch contains 1,000 pcs.	1,000 pcs.	

*Indicate the peak AC and DC values.

Note: For space reasons, the initial letters of the part number "AQY", the SMD terminal shape indicator "A" and the package style indicator "X" or "Z" are not marked on the relay.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY211EH(A)	AQY212EH(A)	AQY210EH(A)	AQY214EH(A)	AQY216EH(A)	Remarks
Input	LED forward current	I _F			50mA			
	LED reverse voltage	V _R			5 V			
	Peak forward current	I _{FP}			1 A		f =100 Hz, Duty factor = 0.1%	
	Power dissipation	P _{in}			75mW			
Output	Load voltage (peak AC)	V _L	30 V	60 V	350 V	400 V	600 V	
	Continuous load current	I _L	1 A	0.55 A	0.13 A	0.12 A	0.05 A	
	Peak load current	I _{peak}	3 A	1.5 A	0.4 A	0.3 A	0.15 A	100 ms (1 shot), V _L = DC
	Power dissipation	P _{out}			500mW			
Total power dissipation		P _T			550mW			
I/O isolation voltage		V _{iso}			5,000 V AC			
Temperature limits	Operating	T _{opr}			-40°C to +85°C -40°F to +185°F		Non-condensing at low temperatures	
	Storage	T _{stg}			-40°C to +100°C -40°F to +212°F			

GU-E PhotoMOS (AQY210EH)

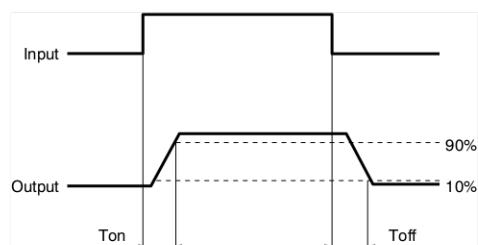
2. Electrical characteristics (Ambient temperature: 25°C 77°F)

	Item	Symbol	AQY211EH(A)	AQY212EH(A)	AQY210EH(A)	AQY214EH(A)	AQY216EH(A)	Condition
Input	LED operate current	Typical Maximum	I_{Fon}		1.2mA			$I_L=Max.$
					3.0mA			
	LED turn off current	Minimum	I_{Foff}		0.4mA			$I_L=Max.$
		Typical			1.1mA			
Output	LED dropout voltage	Typical	V_F		1.25 (1.14 V at $I_f=5mA$)			$I_f=50mA$
		Maximum			1.5V			
	On resistance	Typical	R_{on}	0.25Ω	0.85Ω	18Ω	26Ω	52Ω
		Maximum		0.5Ω	2.5Ω	25Ω	35Ω	120Ω
Transfer characteristics	Off state leakage current	Maximum	I_{Leak}			1μA		$I_f=0mA$ $V_L=Max.$
	Turn on time*	Typical	T_{on}	1.5ms	1ms	0.5ms		$I_f=5mA$
		Maximum		5ms	4ms	2.0ms		$I_L=Max.$
	Turn off time*	Typical	T_{off}	0.1ms	0.05ms	0.08ms	0.04ms	$I_f=5mA$
		Maximum				1.0ms		$I_L=Max.$
I/O capacitance	Typical	C_{iso}			0.8pF			$f = 1MHz$
	Maximum				1.5pF			$V_B = 0V$
Initial I/O isolation resistance	Minimum	R_{iso}				1,000MΩ		500V DC

Note: Recommendable LED forward current $I_f=5$ to 10mA.

Type of connection

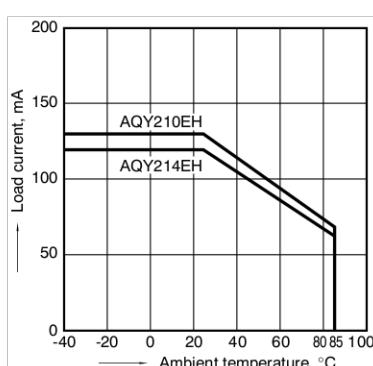
*Turn on/Turn off time



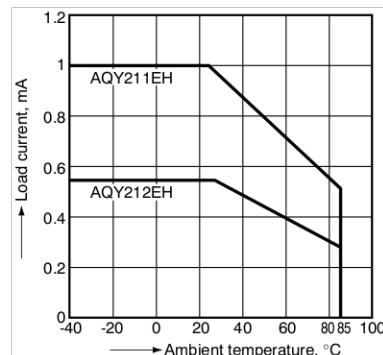
- Dimensions
- Schematic and Wiring Diagrams
- Cautions for Use

REFERENCE DATA

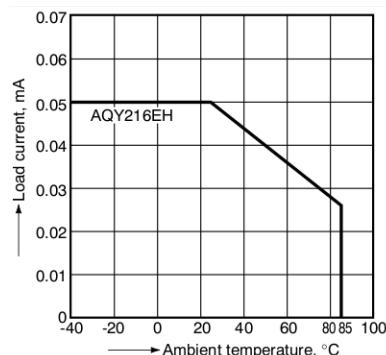
1-(1). Load current vs. ambient temperature characteristics
Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



1-(2). Load current vs. ambient temperature characteristics
Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



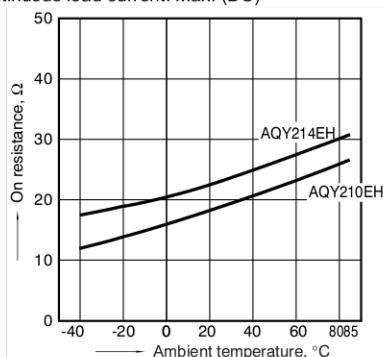
1-(3). Load current vs. ambient temperature characteristics
Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



GU-E PhotoMOS (AQY21OEH)

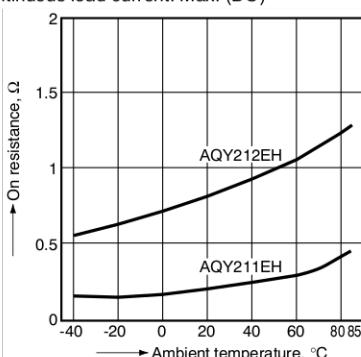
2-(1). On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4;
LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



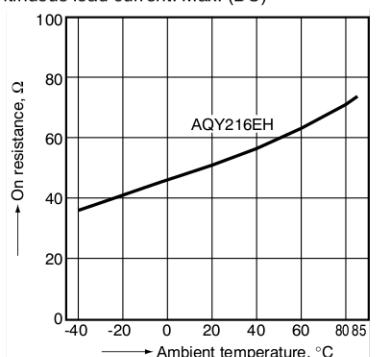
2-(2). On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4;
LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



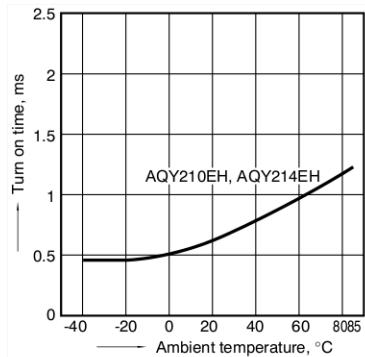
2-(3). On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4;
LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



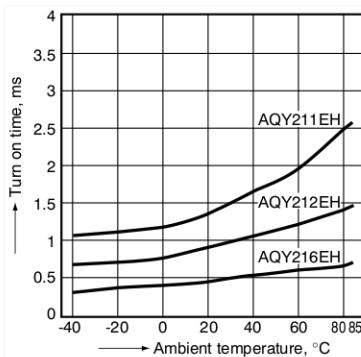
3-(1). Turn on time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



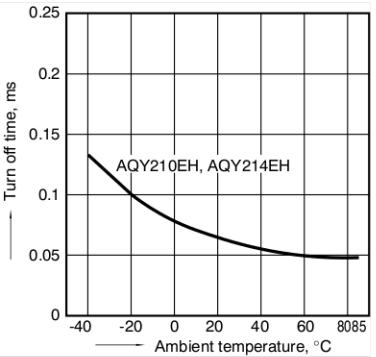
3-(2). Turn on time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



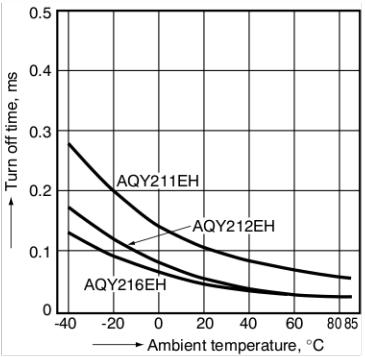
4-(1). Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



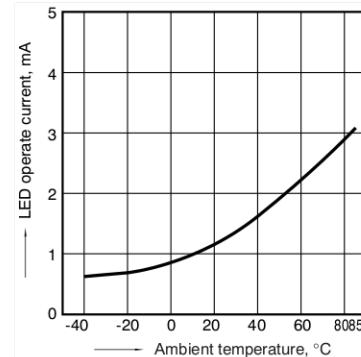
4-(2). Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



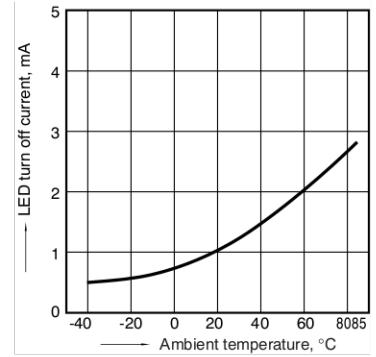
5. LED operate current vs. ambient temperature characteristics

Sample: All types; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



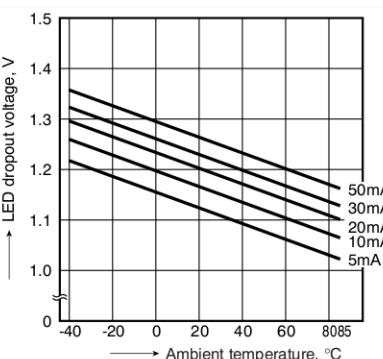
6. LED turn off current vs. ambient temperature characteristics

Sample: All types; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



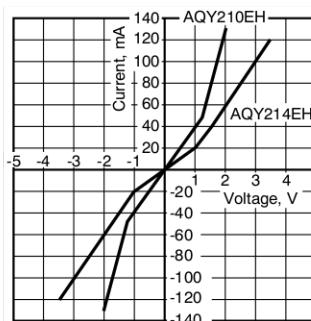
7. LED dropout voltage vs. ambient temperature characteristics

Sample: All types; LED current: 5 to 50 mA



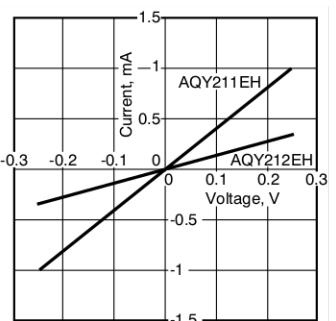
8-(1). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4;
Ambient temperature: 25°C 77°F



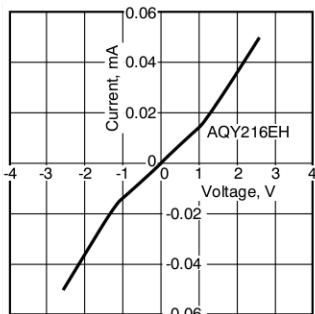
8-(2). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4;
Ambient temperature: 25°C 77°F

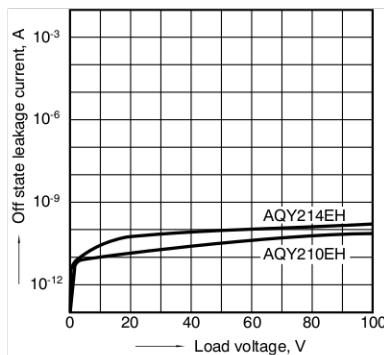


GU-E PhotoMOS (AQY21OEH)

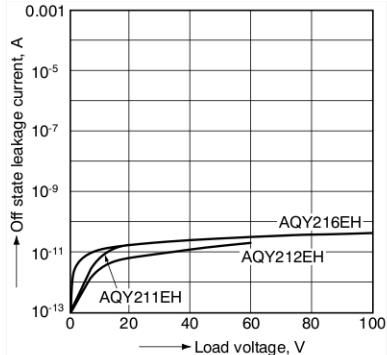
8-(3). Current vs. voltage characteristics of output at MOS portion
 Measured portion: between terminals 3 and 4;
 Ambient temperature: 25°C 77°F



9-(1). Off state leakage current vs. load voltage characteristics
 Measured portion: between terminals 3 and 4;
 Ambient temperature: 25°C 77°F

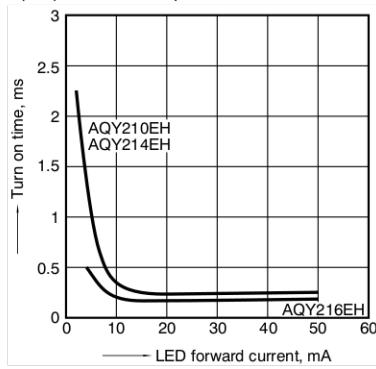


9-(2). Off state leakage current vs. load voltage characteristics
 Measured portion: between terminals 3 and 4;
 Ambient temperature: 25°C 77°F



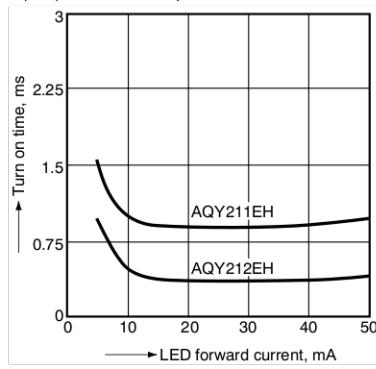
10-(1). Turn on time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4;
 Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



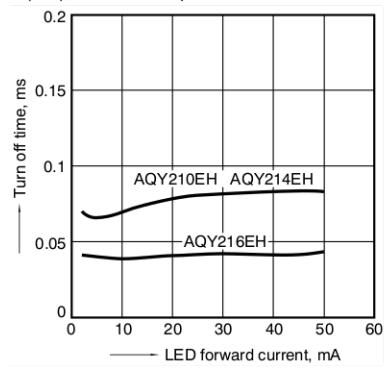
10-(2). Turn on time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4;
 Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



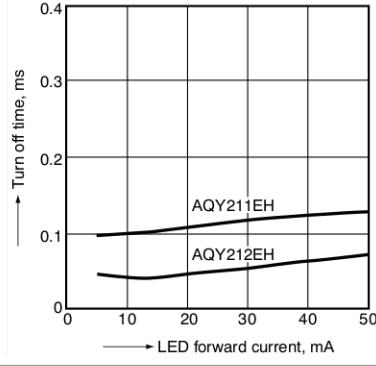
11-(1). Turn off time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4;
 Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



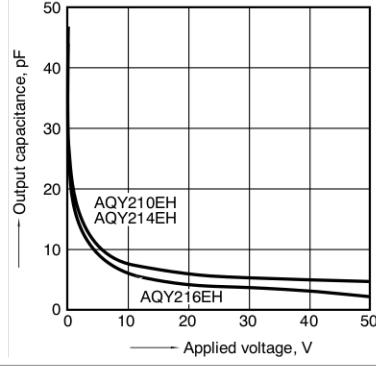
11-(2). Turn off time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4;
 Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



12-(1). Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4;
 Frequency: 1 MHz; Ambient temperature: 25°C 77°F



12-(2). Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4;
 Frequency: 1 MHz; Ambient temperature: 25°C 77°F

